NSN 5961-01-164-4455

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-164-4455 **Inclosure Material:** Metal **Overall Length:** 0.034 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 22.0 breakdown voltage, dc **Current Rating Per Characteristic:** 25.00 milliamperes source cutoff current preset **Capacitance Rating In Picofarads:** 3.2 **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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